

Ordering number:EN5992

P-Channel Silicon MOSFET



FTS1004

DC-DC Converter Applications

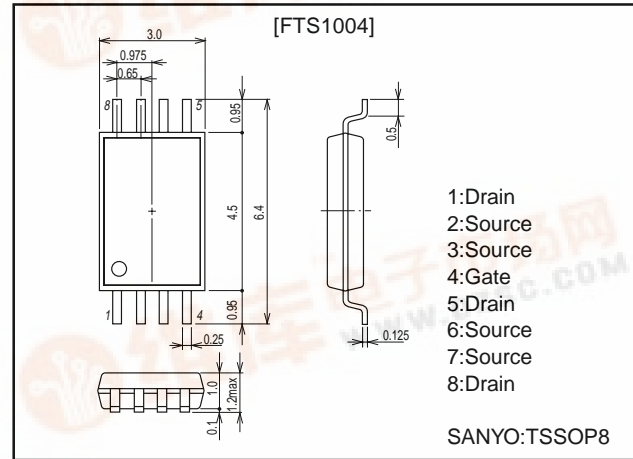
Features

- Low ON Resistance.
- 4V drive.
- Mounting height 1.1mm.

Package Dimensions

unit:mm

2147



Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V _{DSS}		-30	V
Gate-to-Source Voltage	V _{GS}		±20	V
Drain Current (DC)	I _D		-3	A
Drain Current (pulse)	I _{DP}	PW≤10μs, duty cycle≤1%	-15	A
Allowable Power Dissipation	P _D	Mounted on a ceramic board (1000mm ² ×0.8mm)	1.3	W
Channel Temperature	T _{ch}		150	°C
Storage Temperature	T _{stg}		-55 to +150	°C

Electrical Characteristics at Ta = 25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Drain-to-Source Breakdown Voltage	V _{(BR)DSS}	I _D =-1mA, V _{GS} =0	-30			V
Zero-Gate Voltage Drain Current	I _{DSS}	V _{DS} =-30V, V _{GS} =0			-10	μA
Gate-to-Source Leakage Current	I _{GSS}	V _{GS} =±16V, V _{DS} =0			±10	μA
Cutoff Voltage	V _{GS(off)}	V _{DS} =-10V, I _D =-1mA	-1.0		-2.5	V
Forward Transfer Admittance	y _{fs}	V _{DS} =-10V, I _D =-3A	3	5		S
Static Drain-to-Source On-State Resistance	R _{DS(on)1}	I _D =-3A, V _{GS} =-10V		65	85	mΩ
	R _{DS(on)2}	I _D =-1A, V _{GS} =-4V		135	190	mΩ
Input Capacitance	C _{iss}	V _{DS} =-10V, f=1MHz		470		pF
Output Capacitance	C _{oss}	V _{DS} =-10V, f=1MHz		280		pF
Reverse Transfer Capacitance	C _{rss}	V _{DS} =-10V, f=1MHz		140		pF

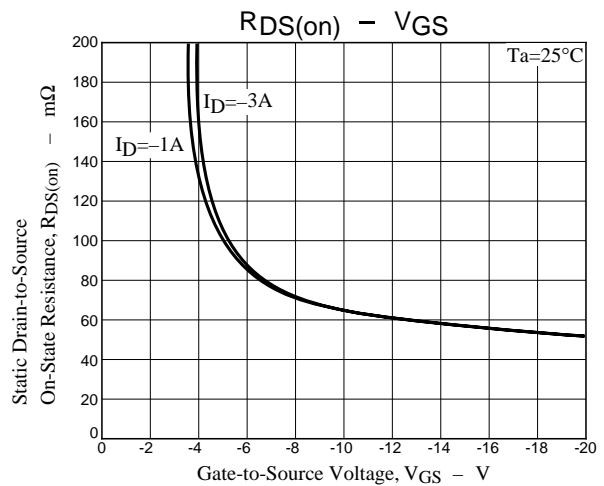
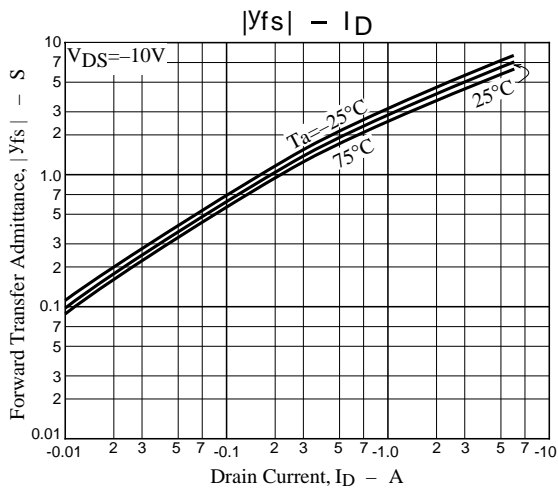
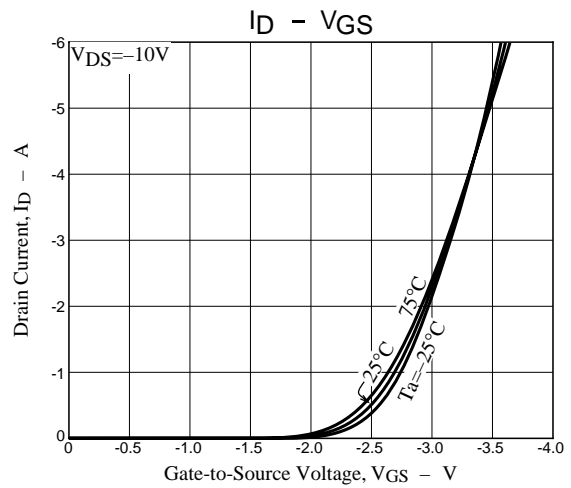
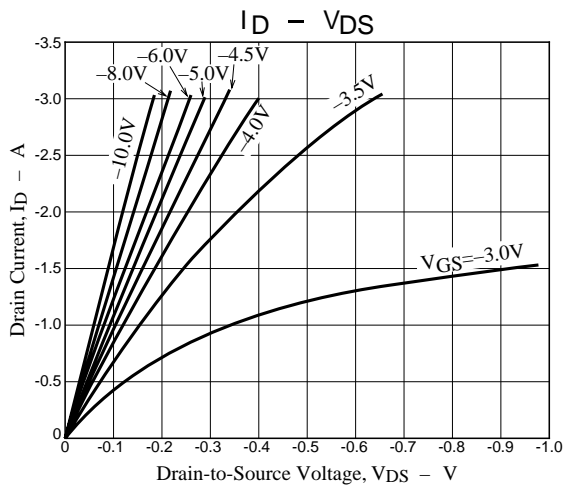
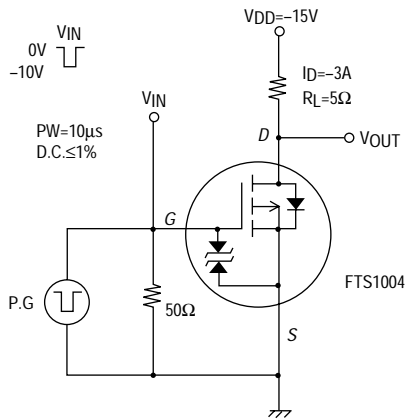
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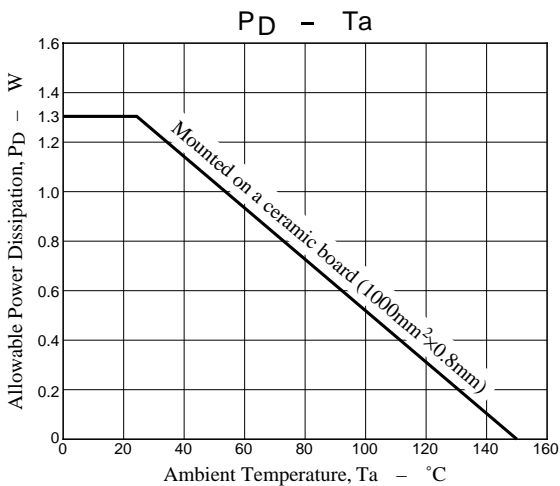
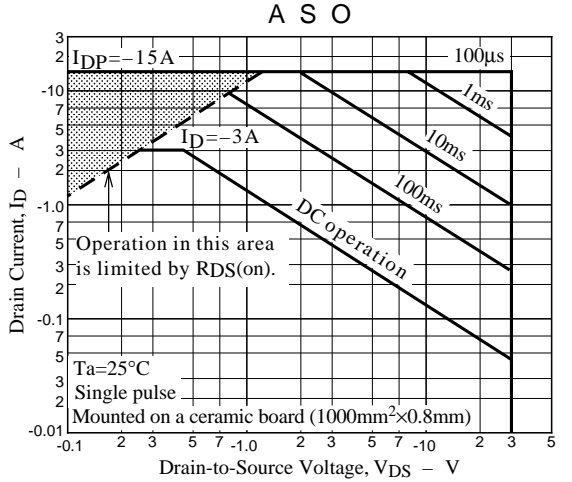
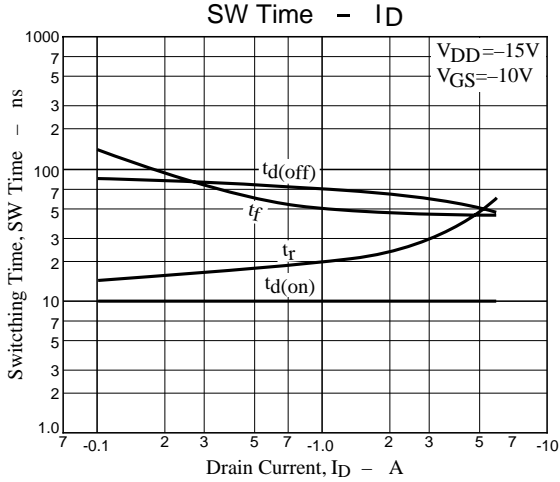
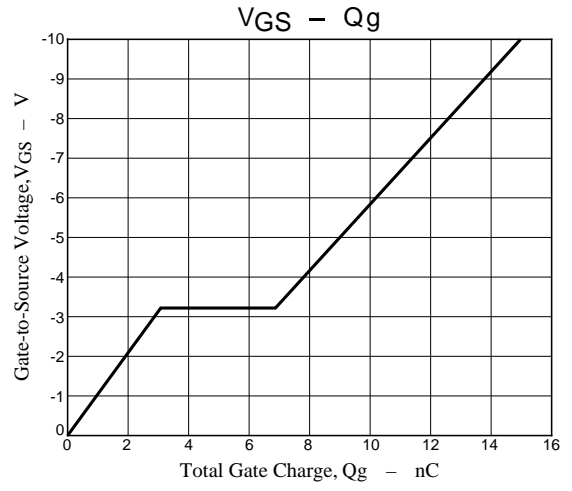
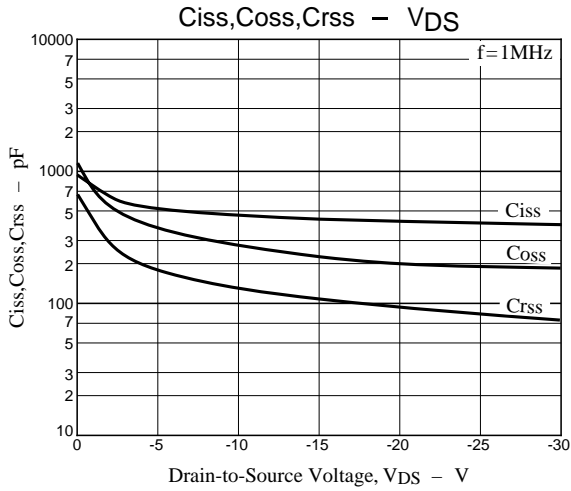
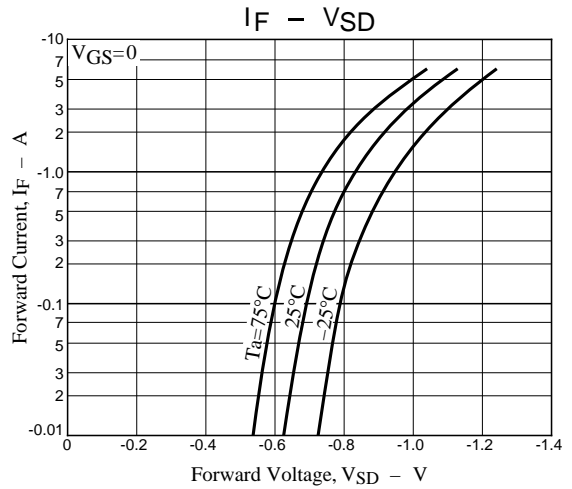
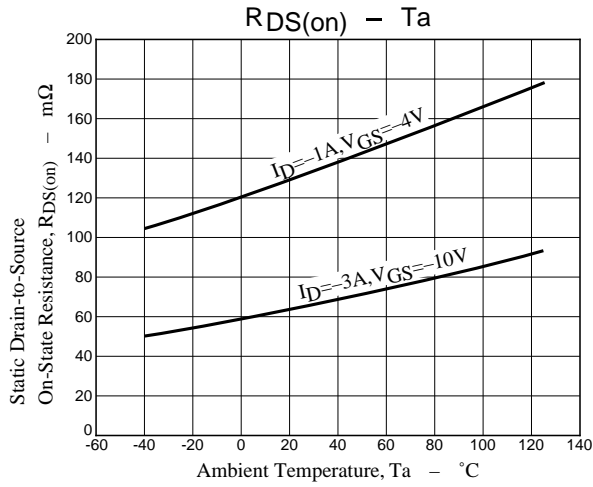
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Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Turn-ON Delay Time	$t_{d(on)}$	See specified Test Circuit		10		ns
Rise Time	t_r	See specified Test Circuit		30		ns
Turn-OFF Delay Time	$t_{d(off)}$	See specified Test Circuit		60		ns
Fall Time	t_f	See specified Test Circuit		45		ns
Total Gate Charge	Q_g	$V_{DS}=-10V, V_{GS}=-10V, I_D=-3A$		15		nC
Gate-to-Source Charge	Q_{gs}	$V_{DS}=-10V, V_{GS}=-10V, I_D=-3A$		3		nC
Gate-to-Drain "Miller" Charge	Q_{gd}	$V_{DS}=-10V, V_{GS}=-10V, I_D=-3A$		4		nC
Diode Forward Voltage	V_{SD}	$I_S=-3A, V_{GS}=0$	-1.0	-1.5		V

Switching Time Test Circuit



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